

SANYO Semiconductors DATA SHEET

DCB010 — Silicon Epitaxial Planar Type (Cathode Common)

Very High-Speed Switching Diode

Features

- · Ideally suited for use in hybrid ICs because of very small-sized package.
- · Fast switching speed.
- · Small interterminal capacitance.

Specifications

Absolute Maximum Ratings at Tc=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Peak Reverse Voltage	V _{RM}		85	V
Reverse Voltage	VR		80	V
D 15 10 1	I _{FM}		300	mA
Peak Forward Current	I _{FM} *		450	mA
A	IO		100	mA
Average Rectified Current	lo*		150	mA
O	IFSM		4	Α
Surge Current (1μs)	IFSM*		6	Α
Allowable Power Dissipation	Р		200	mW
Junction Temperature	Tj		125	°C
Storage Temperature	Tsta		-55 to +125	°C

^{* :} Total value

Electrical Characteristics at Tc=25°C

Parameter	Cymphol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Unit
Forward Voltage	VF1	I _F =1mA		0.60		V
	V _{F2}	I _F =10mA		0.72		V
	VF3	IF=100mA			1.20	V
Reverse Current	I _{R1}	V _R =30V			0.1	μΑ
	IR2	VR=80V			0.5	uА

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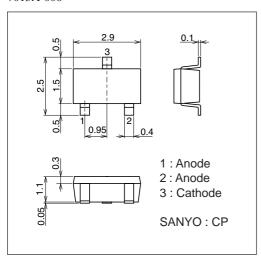
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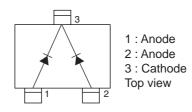
	Parameter	Symbol	Conditions	Ratings			Unit
				min	typ	max	OTIIL
	Interterminal Capacitance	С	V _R =0V, f=1MHz			3.0	pF
	Reverse Recovery Time	trr	I _F =10mA, V_R =6V, R_I =50 Ω , I_{rr} =0.1Irp			4.0	ns

Package Dimensions

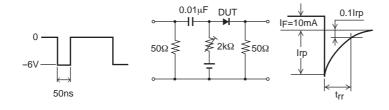
unit : mm (typ) 7013A-006

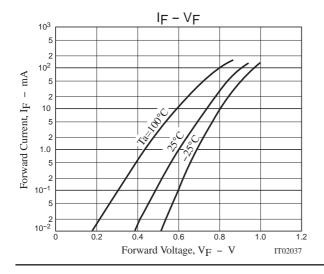


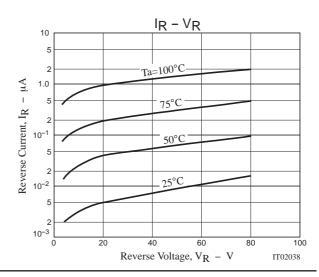
Electrical Connection



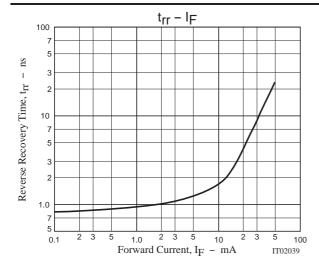
Reverse Recovery Time Test Circuit

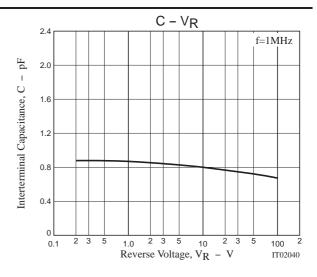






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